



CPH6314 — P-Channel Silicon MOSFET

General-Purpose Switching Device Applications

Features

- Low ON-resistance.
- High-speed switching.
- 4V drive.

Specifications

Absolute Maximum Ratings at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	V_{DSS}		-30	V
Gate-to-Source Voltage	V_{GSS}		± 20	V
Drain Current (DC)	I_D		-4	A
Drain Current (Pulse)	I_{DP}	$PW \leq 10\mu\text{s}$, duty cycle $\leq 1\%$	-16	A
Allowable Power Dissipation	P_D	Mounted on a ceramic board (1200mm ² X0.8mm)	1.6	W
Channel Temperature	T_{ch}		150	$^\circ\text{C}$
Storage Temperature	T_{stg}		-55 to +150	$^\circ\text{C}$

Electrical Characteristics at $T_a=25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Drain-to-Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=-1\text{mA}$, $V_{GS}=0$	-30			V
Zero-Gate Voltage Drain Current	I_{DSS}	$V_{DS}=-30\text{V}$, $V_{GS}=0$			-1	μA
Gate-to-Source Leakage Current	I_{GSS}	$V_{GS}=\pm 16\text{V}$, $V_{DS}=0$			± 10	μA
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=-10\text{V}$, $I_D=-1\text{mA}$	-1.2		-2.6	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=-10\text{V}$, $I_D=-2\text{A}$	2.5	3.6		S
Static Drain-to-Source On-State Resistance	$R_{DS(on)1}$	$I_D=-2\text{A}$, $V_{GS}=-10\text{V}$		53	69	$\text{m}\Omega$
	$R_{DS(on)2}$	$I_D=-1\text{A}$, $V_{GS}=-4.5\text{V}$		92	129	$\text{m}\Omega$
	$R_{DS(on)3}$	$I_D=-1\text{A}$, $V_{GS}=-4\text{V}$		105	147	$\text{m}\Omega$
Input Capacitance	C_{iss}	$V_{DS}=-10\text{V}$, $f=1\text{MHz}$		510		pF
Output Capacitance	C_{oss}	$V_{DS}=-10\text{V}$, $f=1\text{MHz}$		115		pF
Reverse Transfer Capacitance	C_{rss}	$V_{DS}=-10\text{V}$, $f=1\text{MHz}$		78		pF
Turn-ON Delay Time	$t_d(on)$	See specified Test Circuit.		11		ns
Rise Time	t_r	See specified Test Circuit.		20		ns
Turn-OFF Delay Time	$t_d(off)$	See specified Test Circuit.		40		ns
Fall Time	t_f	See specified Test Circuit.		32		ns

Marking : JQ

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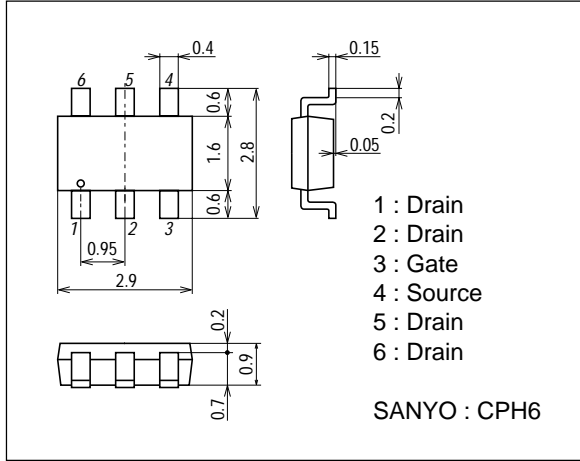
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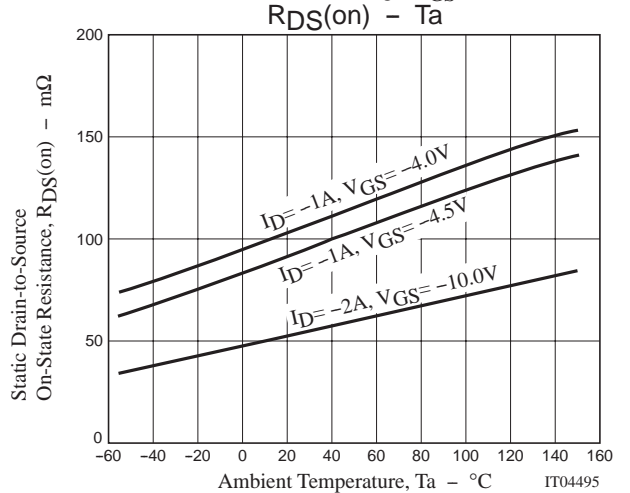
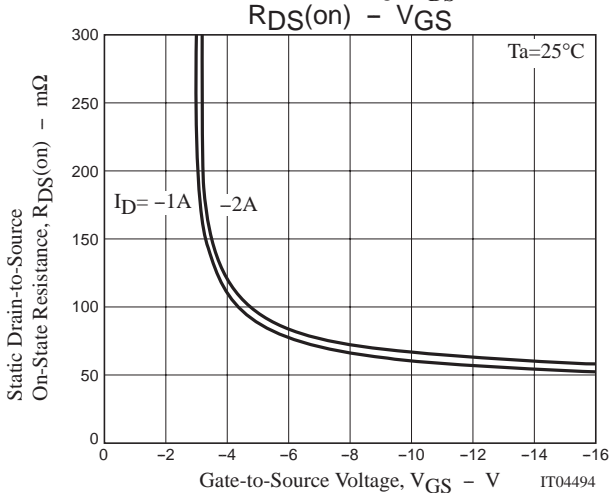
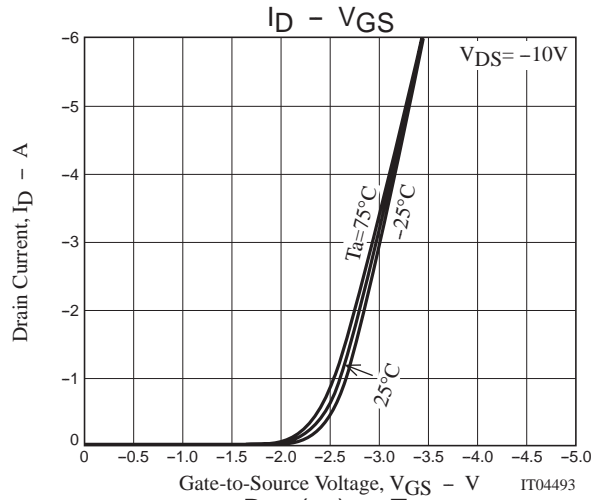
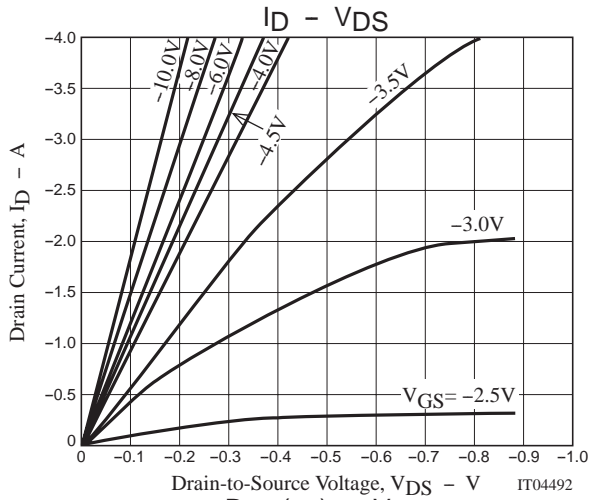
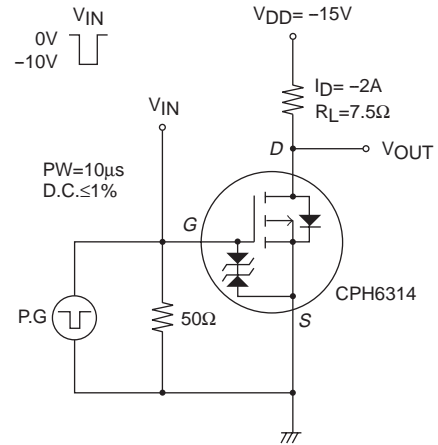
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Total Gate Charge	Qg	$V_{DS}=-10V, V_{GS}=-10V, I_D=-4A$		11		nC
Gate-to-Source Charge	Qgs	$V_{DS}=-10V, V_{GS}=-10V, I_D=-4A$		2.4		nC
Gate-to-Drain "Miller" Charge	Qgd	$V_{DS}=-10V, V_{GS}=-10V, I_D=-4A$		1.7		nC
Diode Forward Voltage	V_{SD}	$I_S=-4A, V_{GS}=0$		-0.86	-1.2	V

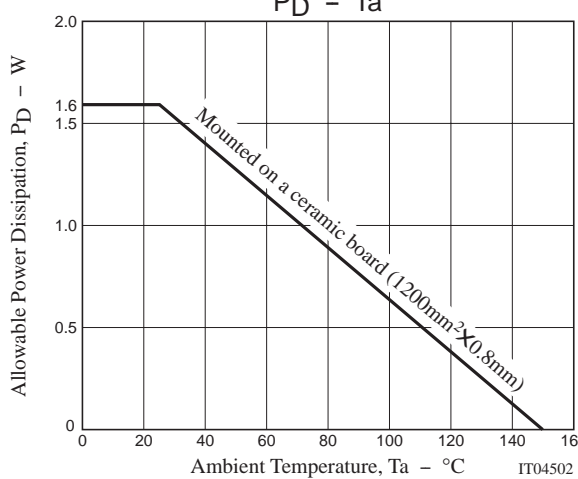
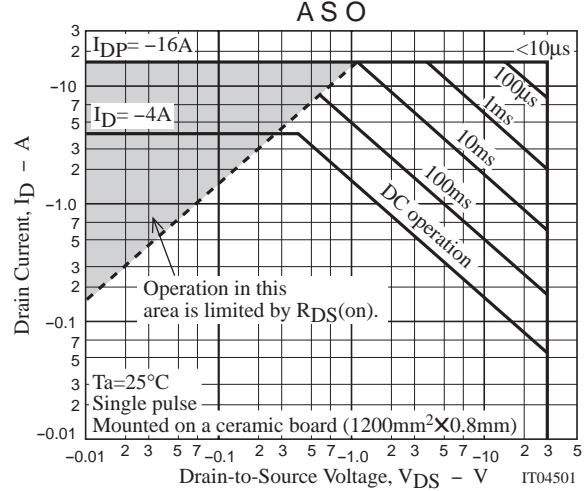
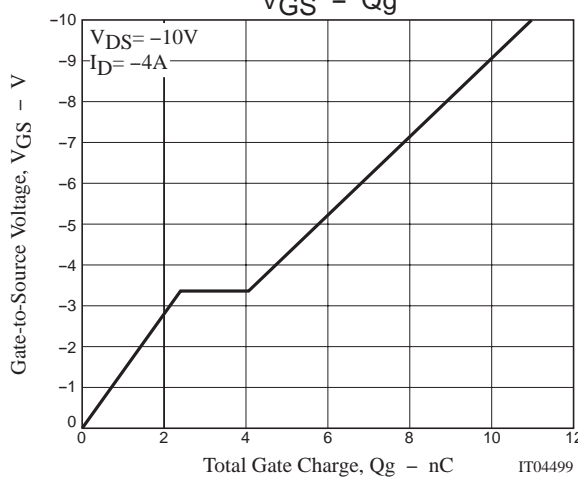
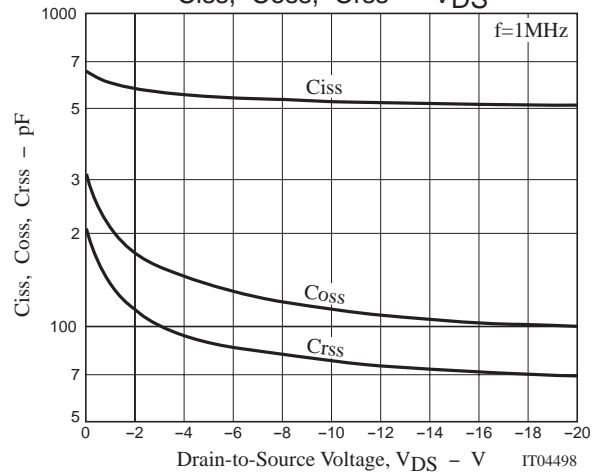
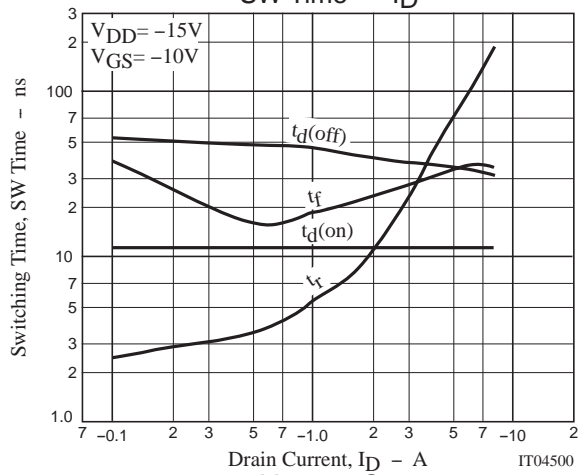
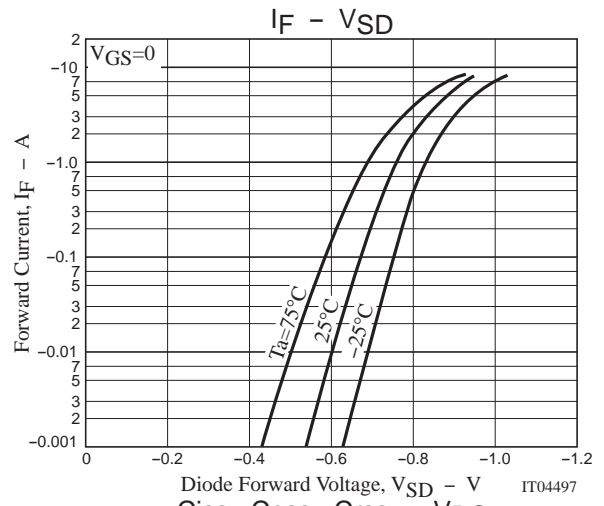
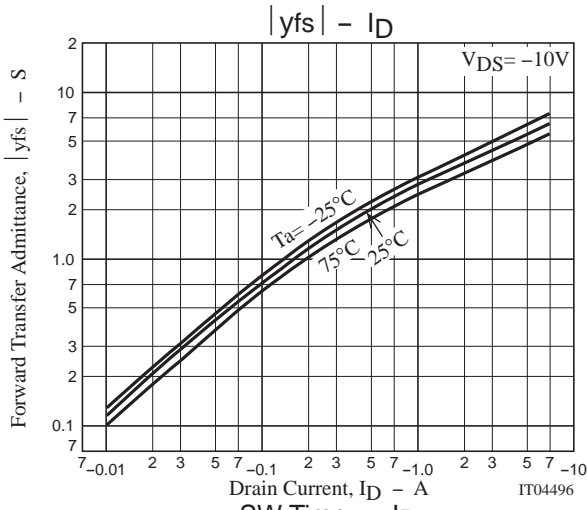
Package Dimensions

unit : mm
2151B



Switching Time Test Circuit





Note on usage : Since the CPH6314 is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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